

# FSFR-Series — Fairchild Power Switch (FPS™) for Half-Bridge Resonant Converters

## Features

- Variable Frequency Control with 50% Duty Cycle for Half-bridge Resonant Converter Topology
- High Efficiency through Zero Voltage Switching (ZVS)
- Internal UniFET™s with Fast-Recovery Type Body Diode ( $t_r < 160\text{ns}$ ).
- Fixed Dead Time (350ns) Optimized for MOSFETs
- Up to 300kHz Operating Frequency
- Pulse Skipping for Frequency Limit (Programmable) at Light-Load Condition
- Remote On/Off Control Using Control Pin
- Protection Functions: Over-Voltage Protection (OVP), Over-Load Protection (OLP), Over-Current Protection (OCP), Abnormal Over-Current Protection (AOCP), Internal Thermal Shutdown (TSD)

## Applications

- PDP and LCD TVs
- Desktop PCs and Servers
- Adapters
- Telecom Power Supplies
- Audio Power Supplies

## Description

The FSFR-series include highly integrated power switches designed for high-efficiency half-bridge resonant converters. Offering everything necessary to build a reliable and robust resonant converter, the FSFR-series simplifies designs and improves productivity, while improving performance. The FSFR-series combines power MOSFETs with fast-recovery type body diodes, a high-side gate-drive circuit, an accurate current controlled oscillator, frequency limit circuit, soft-start, and built-in protection functions. The high-side gate-drive circuit has a common-mode noise cancellation capability, which guarantees stable operation with excellent noise immunity. The fast-recovery body diode of the MOSFETs improves reliability against abnormal operation conditions, while minimizing the effect of the reverse recovery. Using the zero-voltage-switching (ZVS) technique dramatically reduces the switching losses and efficiency is significantly improved. The ZVS also reduces the switching noise noticeably, which allows a small-sized Electromagnetic Interference (EMI) filter.

The FSFR-series can be applied to various resonant converter topologies, such as: series resonant, parallel resonant, and LLC resonant converters.

## Related Resources

[AN-4151 — Half-Bridge LLC Resonant Converter Design Using FSFR-Series Fairchild Power Switch \(FPS™\)](#)

## Ordering Information

| Part Number | Package          | Operating Junction Temperature | $R_{DS(ON\_MAX)}$ | Maximum Output Power without Heatsink ( $V_{IN}=350\sim400V$ ) <sup>(1,2)</sup> | Maximum Output Power with Heatsink ( $V_{IN}=350\sim400V$ ) <sup>(1,2)</sup> |
|-------------|------------------|--------------------------------|-------------------|---------------------------------------------------------------------------------|------------------------------------------------------------------------------|
| FSFR2100U   | 9-SIP            | -40 to +130°C                  | 0.51Ω             | 180W                                                                            | 400W                                                                         |
| FSFR2000    |                  |                                | 0.67Ω             | 160W                                                                            | 350W                                                                         |
| FSFR1900    |                  |                                | 0.85Ω             | 140W                                                                            | 300W                                                                         |
| FSFR1800    |                  |                                | 0.95Ω             | 120W                                                                            | 260W                                                                         |
| FSFR1700    |                  |                                | 1.25Ω             | 100W                                                                            | 200W                                                                         |
| FSFR1600    |                  |                                | 1.55Ω             | 80W                                                                             | 160W                                                                         |
| FSFR1800L   | 9-SIP(L-Forming) | -40 to +130°C                  | 0.95Ω             | 120W                                                                            | 260W                                                                         |
| FSFR1700L   |                  |                                | 1.25Ω             | 100W                                                                            | 200W                                                                         |
| FSFR1600L   |                  |                                | 1.55Ω             | 80W                                                                             | 160W                                                                         |

### Notes:

- The junction temperature can limit the maximum output power.
- Maximum practical continuous power in an open-frame design at 50°C ambient.

## Application Circuit Diagram

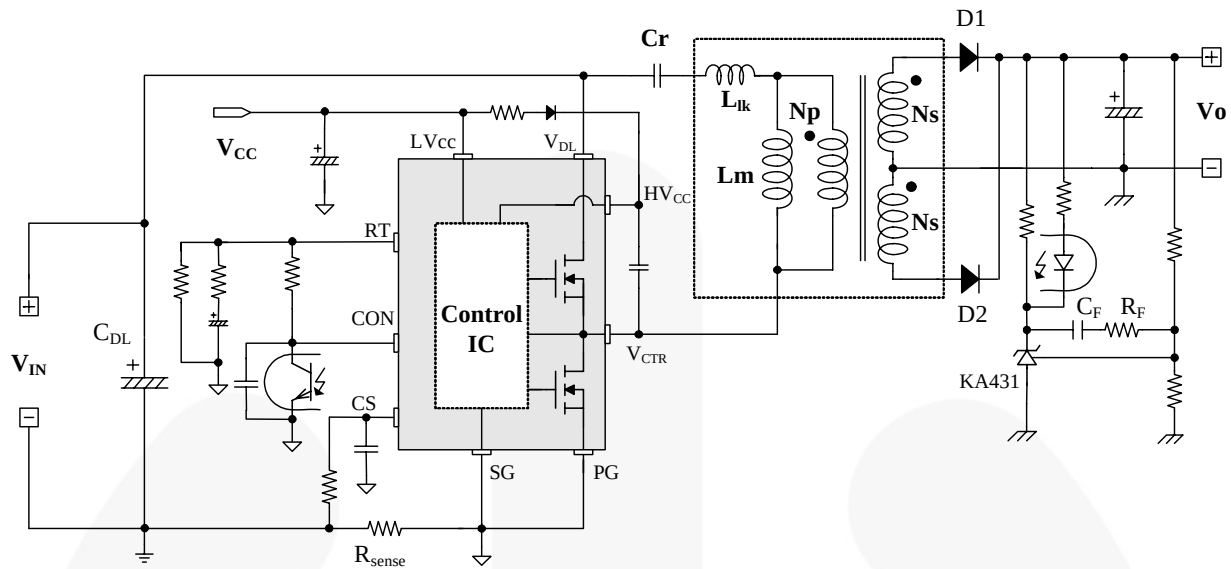


Figure 1. Typical Application Circuit (LLC Resonant Half-Bridge Converter)

## Block Diagram

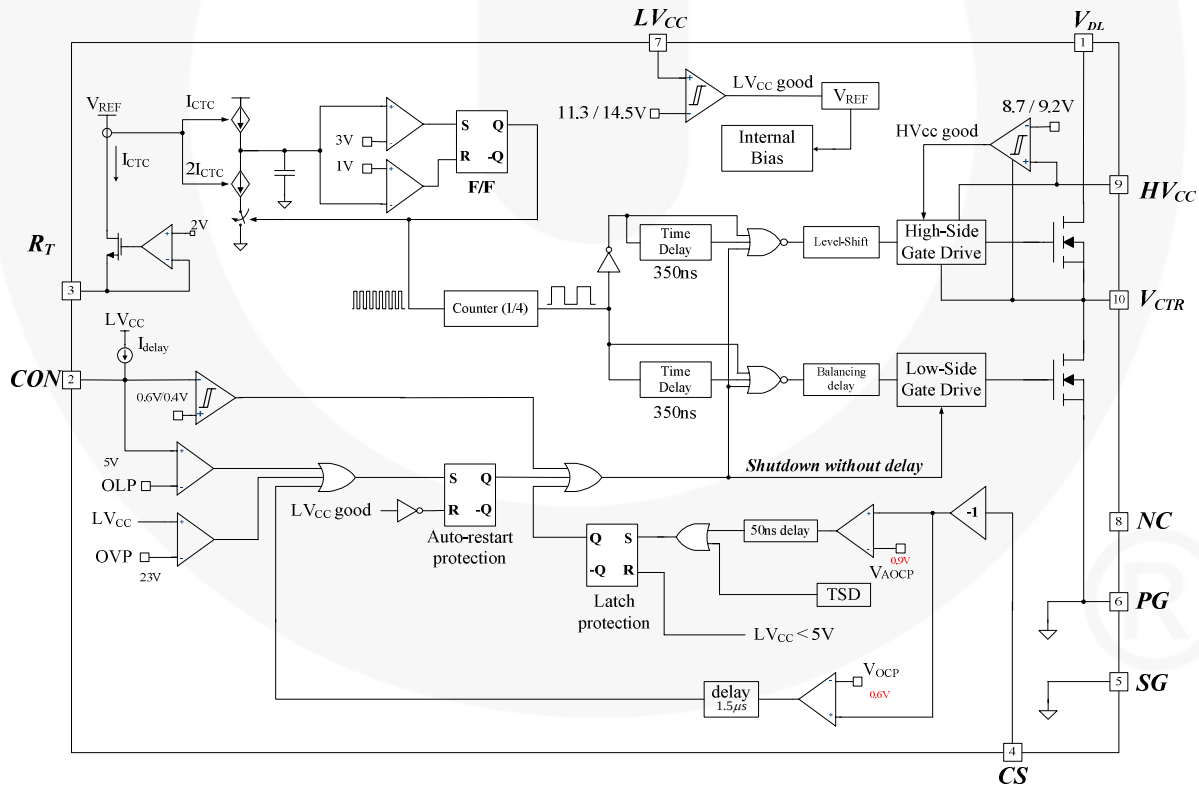


Figure 2. Internal Block Diagram

## Pin Configuration

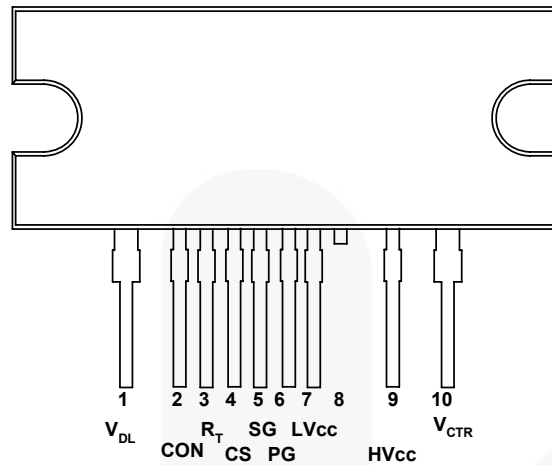


Figure 3. Package Diagram

## Pin Definitions

| Pin # | Name             | Description                                                                                                                                                                                                                                                                                        |
|-------|------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1     | V <sub>DL</sub>  | This is the drain of the high-side MOSFET, typically connected to the input DC link voltage.                                                                                                                                                                                                       |
| 2     | CON              | This pin is for enable/disable and protection. When the voltage of this pin is above 0.6V, the IC operation is enabled. When the voltage of this pin drops below 0.4V, gate drive signals for both MOSFETs are disabled. When the voltage of this pin increases above 5V, protection is triggered. |
| 3     | R <sub>T</sub>   | This pin programs the switching frequency. Typically, an opto-coupler is connected to control the switching frequency for the output voltage regulation.                                                                                                                                           |
| 4     | CS               | This pin senses the current flowing through the low-side MOSFET. Typically, negative voltage is applied on this pin.                                                                                                                                                                               |
| 5     | SG               | This pin is the control ground.                                                                                                                                                                                                                                                                    |
| 6     | PG               | This pin is the power ground. This pin is connected to the source of the low-side MOSFET.                                                                                                                                                                                                          |
| 7     | LV <sub>CC</sub> | This pin is the supply voltage of the control IC.                                                                                                                                                                                                                                                  |
| 8     | NC               | No connection.                                                                                                                                                                                                                                                                                     |
| 9     | HV <sub>CC</sub> | This is the supply voltage of the high-side gate-drive circuit IC.                                                                                                                                                                                                                                 |
| 10    | V <sub>CTR</sub> | This is the drain of the low-side MOSFET. Typically, a transformer is connected to this pin.                                                                                                                                                                                                       |

## Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.  $T_A=25^{\circ}\text{C}$  unless otherwise specified.

| Symbol                 | Parameter                                                             | Min.      | Max.      | Unit               |
|------------------------|-----------------------------------------------------------------------|-----------|-----------|--------------------|
| $V_{DS}$               | Maximum Drain-to-Source Voltage ( $V_{DL}-V_{CTR}$ and $V_{CTR}-PG$ ) | 500       |           | V                  |
| $LV_{CC}$              | Low-Side Supply Voltage                                               | -0.3      | 25.0      | V                  |
| $HV_{CC}$ to $V_{CTR}$ | High-Side $V_{CC}$ Pin to Low-Side Drain Voltage                      | -0.3      | 25.0      | V                  |
| $HV_{CC}$              | High-Side Floating Supply Voltage                                     | -0.3      | 525.0     | V                  |
| $V_{CON}$              | Control Pin Input Voltage                                             | -0.3      | $LV_{CC}$ | V                  |
| $V_{CS}$               | Current Sense (CS) Pin Input Voltage                                  | -5.0      | 1.0       | V                  |
| $V_{RT}$               | $R_T$ Pin Input Voltage                                               | -0.3      | 5.0       | V                  |
| $dV_{CTR}/dt$          | Allowable Low-Side MOSFET Drain Voltage Slew Rate                     |           | 50        | V/ns               |
| $P_D$                  | Total Power Dissipation <sup>(3)</sup>                                | FSFR2100U | 12.0      | W                  |
|                        |                                                                       | FSFR2000  | 12.0      |                    |
|                        |                                                                       | FSFR1900  | 11.8      |                    |
|                        |                                                                       | FSFR1800  | 11.7      |                    |
|                        |                                                                       | FSFR1700  | 11.6      |                    |
|                        |                                                                       | FSFR1600  | 11.5      |                    |
| $T_J$                  | Maximum Junction Temperature <sup>(4)</sup>                           |           | +150      | $^{\circ}\text{C}$ |
|                        | Recommended Operating Junction Temperature <sup>(4)</sup>             | -40       | +130      |                    |
| $T_{STG}$              | Storage Temperature Range                                             | -55       | +150      | $^{\circ}\text{C}$ |
| <b>MOSFET Section</b>  |                                                                       |           |           |                    |
| $V_{DGR}$              | Drain Gate Voltage ( $R_{GS}=1\text{M}\Omega$ )                       | 500       |           | V                  |
| $V_{GS}$               | Gate Source (GND) Voltage                                             |           | $\pm 30$  | V                  |
| $I_{DM}$               | Drain Current Pulsed <sup>(5)</sup>                                   | FSFR2100U | 32        | A                  |
|                        |                                                                       | FSFR2000  | 31        |                    |
|                        |                                                                       | FSFR1900  | 26        |                    |
|                        |                                                                       | FSFR1800  | 23        |                    |
|                        |                                                                       | FSFR1700  | 20        |                    |
|                        |                                                                       | FSFR1600  | 18        |                    |

Continued on the following page...

## Absolute Maximum Ratings (Continued)

| Symbol                     | Parameter                |           | Min.                  | Max. | Unit   |   |
|----------------------------|--------------------------|-----------|-----------------------|------|--------|---|
| MOSFET Section (Continued) |                          |           |                       |      |        |   |
| I <sub>D</sub>             | Continuous Drain Current | FSFR2100U | T <sub>C</sub> =25°C  |      | 10.5   | A |
|                            |                          |           | T <sub>C</sub> =100°C |      | 6.5    |   |
|                            |                          | FSFR2000  | T <sub>C</sub> =25°C  |      | 9.5    |   |
|                            |                          |           | T <sub>C</sub> =100°C |      | 6.0    |   |
|                            |                          | FSFR1900  | T <sub>C</sub> =25°C  |      | 8.0    |   |
|                            |                          |           | T <sub>C</sub> =100°C |      | 5.0    |   |
|                            |                          | FSFR1800  | T <sub>C</sub> =25°C  |      | 7.0    |   |
|                            |                          |           | T <sub>C</sub> =100°C |      | 4.5    |   |
|                            |                          | FSFR1700  | T <sub>C</sub> =25°C  |      | 6.0    |   |
|                            |                          |           | T <sub>C</sub> =100°C |      | 3.9    |   |
|                            |                          | FSFR1600  | T <sub>C</sub> =25°C  |      | 4.5    |   |
|                            |                          |           | T <sub>C</sub> =100°C |      | 2.7    |   |
| Package Section            |                          |           |                       |      |        |   |
| Torque                     | Recommended Screw Torque |           | 5~7                   |      | kgf-cm |   |

### Notes:

- Per MOSFET when both MOSFETs are conducting.
- The maximum value of the recommended operating junction temperature is limited by thermal shutdown.
- Pulse width is limited by maximum junction temperature.

## Thermal Impedance

$T_A=25^{\circ}\text{C}$  unless otherwise specified.

| Symbol        | Parameter                                                              |           | Value | Unit                 |
|---------------|------------------------------------------------------------------------|-----------|-------|----------------------|
| $\theta_{JC}$ | Junction-to-Case Center Thermal Impedance<br>(Both MOSFETs Conducting) | FSFR2100U | 10.44 | $^{\circ}\text{C/W}$ |
|               |                                                                        | FSFR2000  | 10.44 |                      |
|               |                                                                        | FSFR1900  | 10.56 |                      |
|               |                                                                        | FSFR1800  | 10.68 |                      |
|               |                                                                        | FSFR1700  | 10.79 |                      |
|               |                                                                        | FSFR1600  | 10.89 |                      |

## Electrical Characteristics

T<sub>A</sub>=25°C unless otherwise specified.

| Symbol              | Parameter                                             |                                                   | Test Conditions                                | Min. | Typ. | Max. | Unit |
|---------------------|-------------------------------------------------------|---------------------------------------------------|------------------------------------------------|------|------|------|------|
| MOSFET Section      |                                                       |                                                   |                                                |      |      |      |      |
| BV <sub>DSS</sub>   | Drain-to-Source Breakdown Voltage                     |                                                   | I <sub>D</sub> =200μA, T <sub>A</sub> =25°C    | 500  |      |      | V    |
|                     |                                                       |                                                   | I <sub>D</sub> =200μA, T <sub>A</sub> =125°C   |      | 540  |      |      |
| R <sub>DS(ON)</sub> | On-State Resistance                                   | FSFR2100U                                         | V <sub>GS</sub> =10V, I <sub>D</sub> =6.0A     |      | 0.41 | 0.51 | Ω    |
|                     |                                                       | FSFR2000                                          | V <sub>GS</sub> =10V, I <sub>D</sub> =5.0A     |      | 0.53 | 0.67 |      |
|                     |                                                       | FSFR1900                                          | V <sub>GS</sub> =10V, I <sub>D</sub> =4.0A     |      | 0.74 | 0.85 |      |
|                     |                                                       | FSFR1800                                          | V <sub>GS</sub> =10V, I <sub>D</sub> =3.0A     |      | 0.77 | 0.95 |      |
|                     |                                                       | FSFR1700                                          | V <sub>GS</sub> =10V, I <sub>D</sub> =2.0A     |      | 1.00 | 1.25 |      |
|                     |                                                       | FSFR1600                                          | V <sub>GS</sub> =10V, I <sub>D</sub> =2.25A    |      | 1.25 | 1.55 |      |
| t <sub>rr</sub>     | Body Diode Reverse Recovery Time <sup>(6)</sup>       |                                                   | di <sub>Diode</sub> /dt=100A/μs                |      |      |      | ns   |
|                     |                                                       | FSFR2100U                                         | V <sub>GS</sub> =0V, I <sub>Diode</sub> =12.0A |      | 120  |      |      |
|                     |                                                       | FSFR2000                                          | V <sub>GS</sub> =0V, I <sub>Diode</sub> =9.5A  |      | 125  |      |      |
|                     |                                                       | FSFR1900                                          | V <sub>GS</sub> =0V, I <sub>Diode</sub> =8.0A  |      | 140  |      |      |
|                     |                                                       | FSFR1800                                          | V <sub>GS</sub> =0V, I <sub>Diode</sub> =7.0A  |      | 160  |      |      |
|                     |                                                       | FSFR1700                                          | V <sub>GS</sub> =0V, I <sub>Diode</sub> =6.0A  |      | 160  |      |      |
|                     |                                                       | FSFR1600                                          | V <sub>GS</sub> =0V, I <sub>Diode</sub> =5.0A  |      | 65   |      |      |
| Supply Section      |                                                       |                                                   |                                                |      |      |      |      |
| I <sub>LK</sub>     | Offset Supply Leakage Current                         | H-V <sub>CC</sub> =V <sub>CTR</sub> =600V/500V    |                                                |      |      | 50   | μA   |
| I <sub>QHVCC</sub>  | Quiescent HV <sub>CC</sub> Supply Current             | (HV <sub>CC</sub> UV+) - 0.1V                     |                                                |      | 50   | 120  | μA   |
| I <sub>QLVCC</sub>  | Quiescent LV <sub>CC</sub> Supply Current             | (LV <sub>CC</sub> UV+) - 0.1V                     |                                                |      | 100  | 200  | μA   |
| I <sub>OHVCC</sub>  | Operating HV <sub>CC</sub> Supply Current (RMS Value) | f <sub>OSC</sub> =100KHz, V <sub>CON</sub> > 0.6V |                                                |      | 6    | 9    | mA   |
|                     |                                                       | No Switching, V <sub>CON</sub> < 0.4V             |                                                |      | 100  | 200  | μA   |
| I <sub>OLVCC</sub>  | Operating LV <sub>CC</sub> Supply Current (RMS Value) | f <sub>OSC</sub> =100KHz, V <sub>CON</sub> > 0.6V |                                                |      | 7    | 11   | mA   |
|                     |                                                       | No Switching, V <sub>CON</sub> < 0.4V             |                                                |      | 2    | 4    | mA   |

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**Electrical Characteristics** (Continued)T<sub>A</sub>=25°C unless otherwise specified.

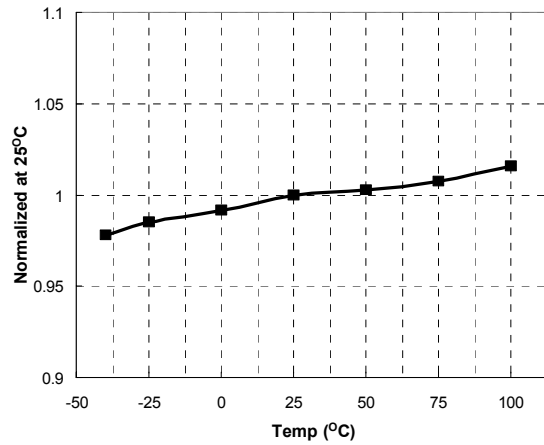
| Symbol                                   | Parameter                                                                               | Test Conditions                                                 | Min.  | Typ.  | Max.  | Unit |
|------------------------------------------|-----------------------------------------------------------------------------------------|-----------------------------------------------------------------|-------|-------|-------|------|
| <b>UVLO Section</b>                      |                                                                                         |                                                                 |       |       |       |      |
| LV <sub>CC</sub> UV+                     | LV <sub>CC</sub> Supply Under-Voltage Positive Going Threshold (LV <sub>CC</sub> Start) |                                                                 | 13.0  | 14.5  | 16.0  | V    |
| LV <sub>CC</sub> UV-                     | LV <sub>CC</sub> Supply Under-Voltage Negative Going Threshold (LV <sub>CC</sub> Stop)  |                                                                 | 10.2  | 11.3  | 12.4  | V    |
| LV <sub>CC</sub> UVH                     | LV <sub>CC</sub> Supply Under-Voltage Hysteresis                                        |                                                                 |       | 3.2   |       | V    |
| HV <sub>CC</sub> UV+                     | HV <sub>CC</sub> Supply Under-Voltage Positive Going Threshold (HV <sub>CC</sub> Start) |                                                                 | 8.2   | 9.2   | 10.2  | V    |
| HV <sub>CC</sub> UV-                     | HV <sub>CC</sub> Supply Under-Voltage Negative Going Threshold (HV <sub>CC</sub> Stop)  |                                                                 | 7.8   | 8.7   | 9.6   | V    |
| HV <sub>CC</sub> UVH                     | HV <sub>CC</sub> Supply Under-Voltage Hysteresis                                        |                                                                 |       | 0.5   |       | V    |
| <b>Oscillator &amp; Feedback Section</b> |                                                                                         |                                                                 |       |       |       |      |
| V <sub>CONDIS</sub>                      | Control Pin Disable Threshold Voltage                                                   |                                                                 | 0.36  | 0.40  | 0.44  | V    |
| V <sub>CONEN</sub>                       | Control Pin Enable Threshold Voltage                                                    |                                                                 | 0.54  | 0.60  | 0.66  | V    |
| V <sub>RT</sub>                          | V-I Converter Threshold Voltage                                                         | R <sub>T</sub> =5.2KΩ                                           | 1.5   | 2.0   | 2.5   | V    |
| f <sub>OSC</sub>                         | Output Oscillation Frequency                                                            |                                                                 | 94    | 100   | 106   | KHz  |
| DC                                       | Output Duty Cycle                                                                       |                                                                 | 48    | 50    | 52    | %    |
| f <sub>SS</sub>                          | Internal Soft-Start Initial Frequency                                                   | f <sub>SS</sub> =f <sub>OSC</sub> +40kHz, R <sub>T</sub> =5.2KΩ |       | 140   |       | KHz  |
| t <sub>SS</sub>                          | Internal Soft-Start Time                                                                |                                                                 | 2     | 3     | 4     | ms   |
| <b>Protection Section</b>                |                                                                                         |                                                                 |       |       |       |      |
| I <sub>OLP</sub>                         | OLP Delay Current                                                                       | V <sub>CON</sub> =4V                                            | 3.6   | 4.8   | 6.0   | μA   |
| V <sub>OLP</sub>                         | OLP Protection Voltage                                                                  | V <sub>CON</sub> > 3.5V                                         | 4.5   | 5.0   | 5.5   | V    |
| V <sub>OV</sub>                          | LV <sub>CC</sub> Over-Voltage Protection                                                | L-V <sub>CC</sub> > 21V                                         | 21    | 23    | 25    | V    |
| V <sub>AOCP</sub>                        | AOCP Threshold Voltage                                                                  | ΔV/Δt=-0.1V/μs                                                  | -1.0  | -0.9  | -0.8  | V    |
| t <sub>BAO</sub>                         | AOCP Blanking Time <sup>(6)</sup>                                                       | V <sub>CS</sub> < V <sub>AOCP</sub> ; ΔV/Δt=-0.1V/μs            |       | 50    |       | ns   |
| V <sub>OCP</sub>                         | OCP Threshold Voltage                                                                   | V/Δt=-1V/μs                                                     | -0.64 | -0.58 | -0.52 | V    |
| t <sub>BO</sub>                          | OCP Blanking Time <sup>(6)</sup>                                                        | V <sub>CS</sub> < V <sub>OCP</sub> ; ΔV/Δt=-1V/μs               | 1.0   | 1.5   | 2.0   | μs   |
| t <sub>DA</sub>                          | Delay Time (Low Side) Detecting from V <sub>AOCP</sub> to Switch Off <sup>(6)</sup>     | ΔV/Δt=-1V/μs                                                    |       | 250   | 400   | ns   |
| T <sub>SD</sub>                          | Thermal Shutdown Temperature <sup>(6)</sup>                                             |                                                                 | 110   | 130   | 150   | °C   |
| I <sub>SU</sub>                          | Protection Latch Sustain LV <sub>CC</sub> Supply Current                                | LV <sub>CC</sub> =7.5V                                          |       | 100   | 150   | μA   |
| V <sub>PRSET</sub>                       | Protection Latch Reset LV <sub>CC</sub> Supply Voltage                                  |                                                                 | 5     |       |       | V    |
| <b>Dead-Time Control Section</b>         |                                                                                         |                                                                 |       |       |       |      |
| D <sub>T</sub>                           | Dead Time <sup>(7)</sup>                                                                |                                                                 |       | 350   |       | ns   |

**Notes:**

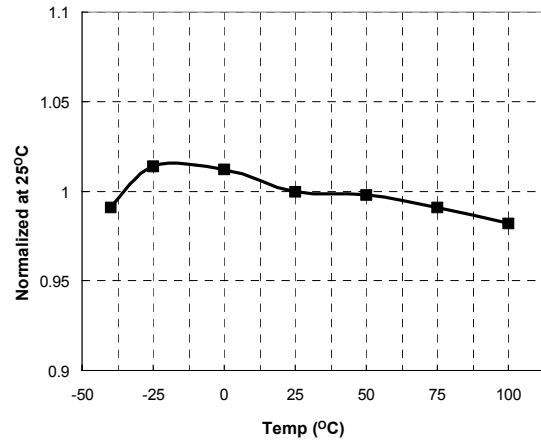
6. This parameter, although guaranteed, is not tested in production.  
 7. These parameters, although guaranteed, are tested only in EDS (wafer test) process.

## Typical Performance Characteristics

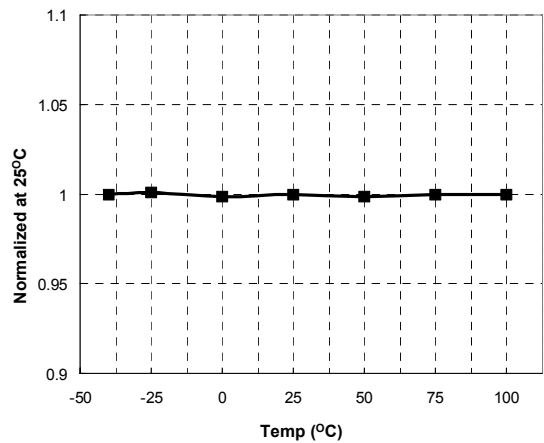
These characteristic graphs are normalized at  $T_A=25^\circ\text{C}$ .



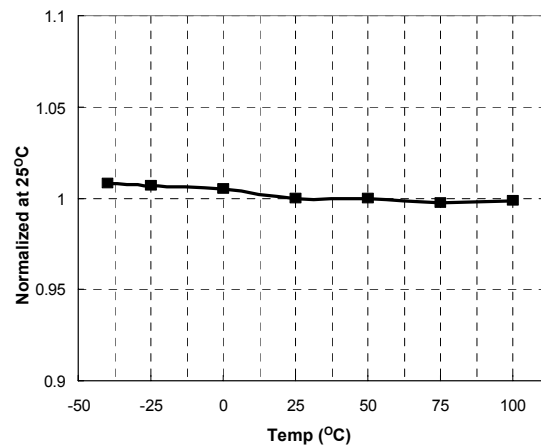
**Figure 4. Low-Side MOSFET Duty Cycle vs. Temperature**



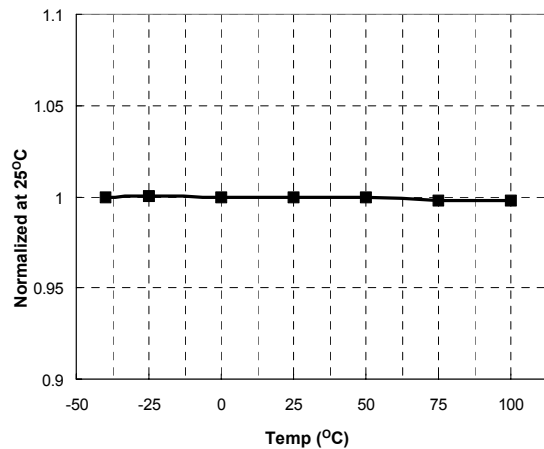
**Figure 5. Switching Frequency vs. Temperature**



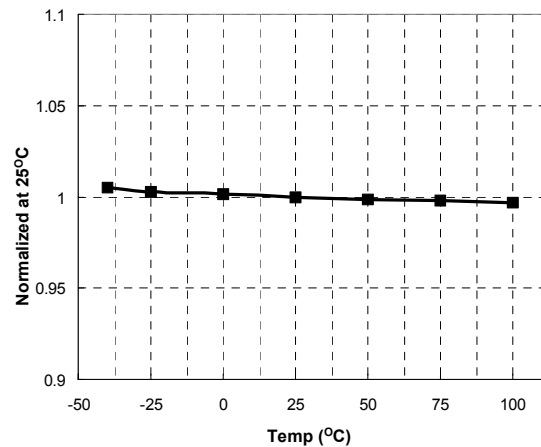
**Figure 6. High-Side  $V_{CC}$  ( $HV_{CC}$ ) Start vs. Temperature**



**Figure 7. High-Side  $V_{CC}$  ( $HV_{CC}$ ) Stop vs. Temperature**



**Figure 8. Low-Side  $V_{CC}$  ( $LV_{CC}$ ) Start vs. Temperature**



**Figure 9. Low-Side  $V_{CC}$  ( $LV_{CC}$ ) Stop vs. Temperature**



## Typical Performance Characteristics (Continued)

These characteristic graphs are normalized at  $T_A=25^\circ\text{C}$ .

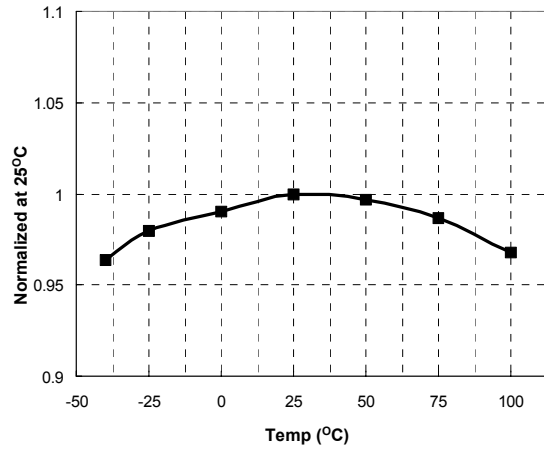


Figure 10. OLP Delay Current vs. Temperature

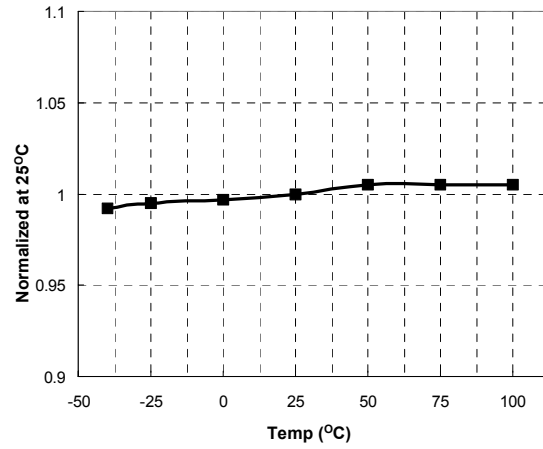


Figure 11. OLP Protection Voltage vs. Temperature

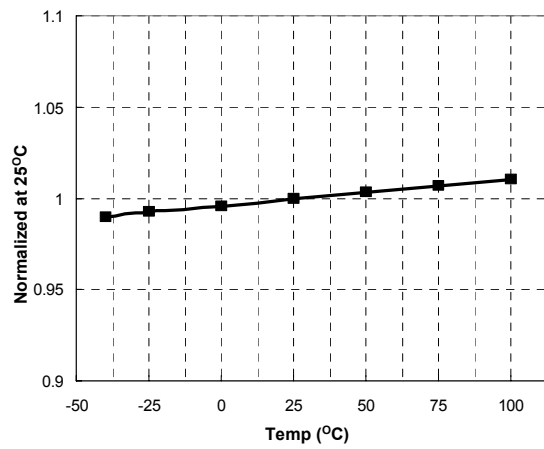


Figure 12. LVCC OVP Voltage vs. Temperature

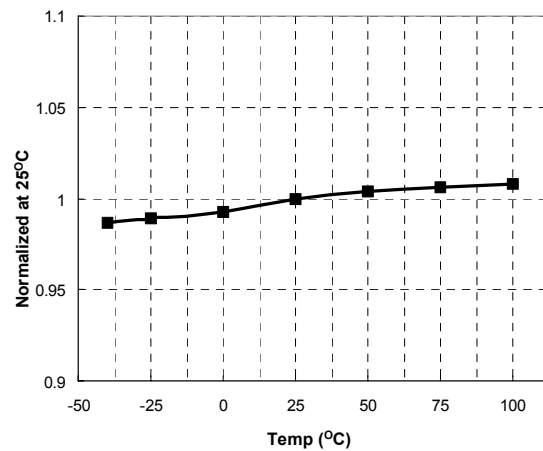


Figure 13.  $R_T$  Voltage vs. Temperature

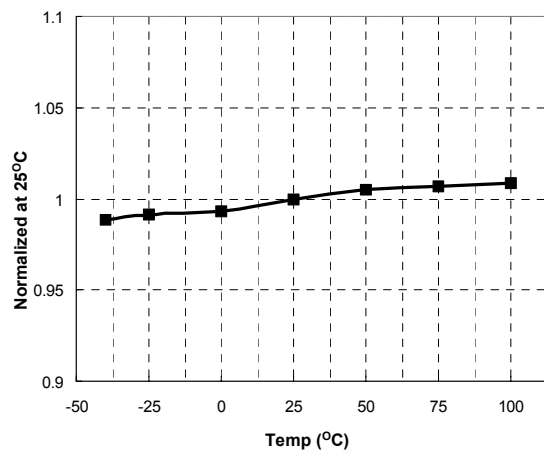


Figure 14. CON Pin Enable Voltage vs. Temperature

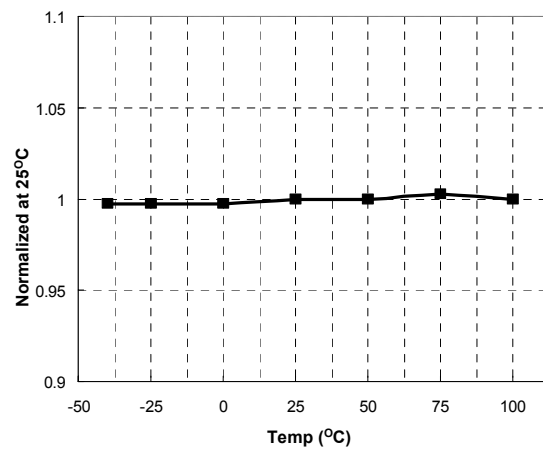


Figure 15. OCP Voltage vs. Temperature

## Functional Description

**1. Basic Operation:** FSFR-series is designed to drive high-side and low-side MOSFETs complementarily with 50% duty cycle. A fixed dead time of 350ns is introduced between consecutive transitions, as shown in Figure 16.

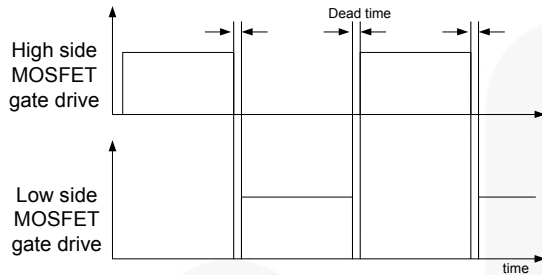


Figure 16. MOSFETs Gate Drive Signal

**2. Internal Oscillator:** FSFR-series employs a current-controlled oscillator, as shown in Figure 17. Internally, the voltage of  $R_T$  pin is regulated at 2V and the charging/discharging current for the oscillator capacitor,  $C_T$ , is obtained by copying the current flowing out of  $R_T$  pin ( $I_{CTC}$ ) using a current mirror. Therefore, the switching frequency increases as  $I_{CTC}$  increases.

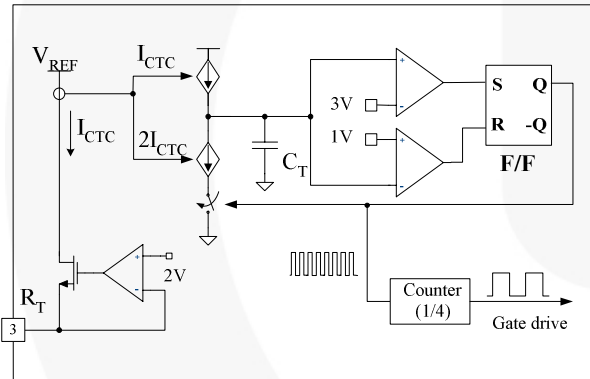


Figure 17. Current Controlled Oscillator

**3. Frequency Setting:** Figure 18 shows the typical voltage gain curve of a resonant converter, where the gain is inversely proportional to the switching frequency in the ZVS region. The output voltage can be regulated by modulating the switching frequency. Figure 19 shows the typical circuit configuration for  $R_T$  pin, where the opto-coupler transistor is connected to the  $R_T$  pin to modulate the switching frequency.

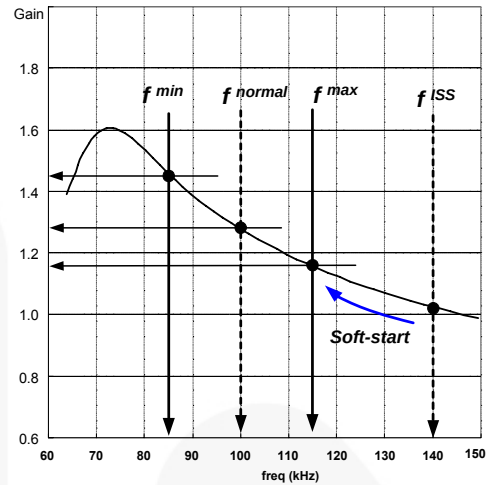


Figure 18. Resonant Converter Typical Gain Curve

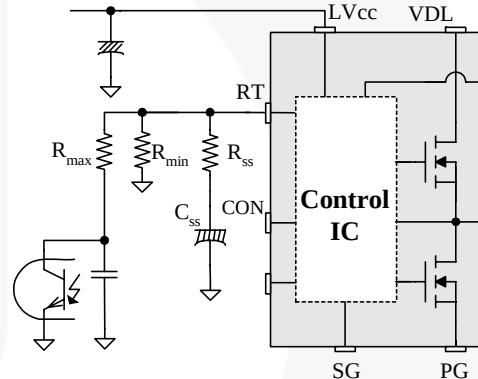


Figure 19. Frequency Control Circuit

The minimum switching frequency is determined as:

$$f_{\min} = \frac{5.2k\Omega}{R_{\min}} \times 100(\text{kHz}) \quad (1)$$

Assuming the saturation voltage of opto-coupler transistor is 0.2V, the maximum switching frequency is determined as:

$$f_{\max} = \left( \frac{5.2k\Omega}{R_{\min}} + \frac{4.68k\Omega}{R_{\max}} \right) \times 100(\text{kHz}) \quad (2)$$

To prevent excessive inrush current and overshoot of output voltage during startup, increase the voltage gain of the resonant converter progressively. Since the voltage gain of the resonant converter is inversely proportional to the switching frequency, the soft-start is implemented by sweeping down the switching frequency from an initial high frequency ( $f^{ISS}$ ) until the output voltage is established. The soft-start circuit is made by connecting R-C series network on the  $R_T$  pin, as shown

in Figure 19. FSFR-series also has an internal soft-start for 3ms to reduce the current overshoot during the initial cycles, which adds 40kHz to the initial frequency of the external soft-start circuit, as shown in Figure 20. The initial frequency of the soft-start is given as:

$$f_{ISS} = \left( \frac{5.2k\Omega}{R_{min}} + \frac{5.2k\Omega}{R_{SS}} \right) \times 100 + 40 \text{ (kHz)} \quad (3)$$

It is typical to set the initial frequency of soft-start two ~ three times the resonant frequency ( $f_o$ ) of the resonant network.

The soft-start time is three to four times of the RC time constant. The RC time constant is as follows:

$$T_{SS} = R_{SS} \cdot C_{SS} \quad (4)$$

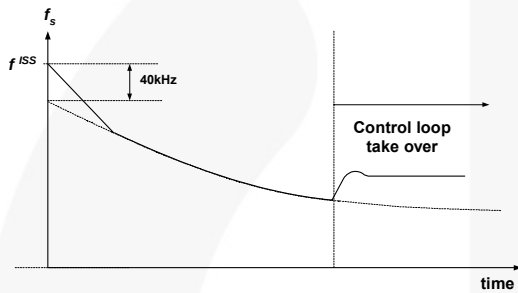


Figure 20. Frequency Sweeping of Soft-start

**4. Control Pin:** The FSFR-series has a control pin for protection, cycle skipping, and remote on/off. Figure 21 shows the internal block diagram for control pin.

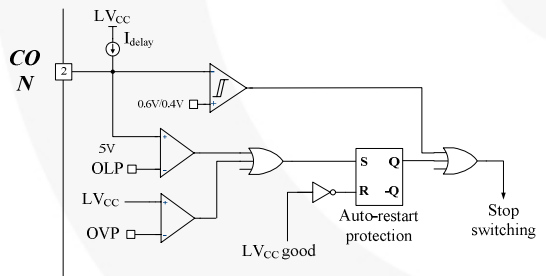


Figure 21. Internal Block of Control Pin

**Protection:** When the control pin voltage exceeds 5V, protection is triggered. Detailed applications are described in the protection section.

**Pulse Skipping:** FSFR-series stops switching when the control pin voltage drops below 0.4V and resumes switching when the control pin voltage rises above 0.6V. To use pulse-skipping, the control pin should be connected to the opto-coupler collector pin. The frequency that causes pulse skipping is given as:

$$f^{SKIP} = \left( \frac{5.2k\Omega}{R_{min}} + \frac{4.16k\Omega}{R_{max}} \right) \times 100 \text{ (kHz)} \quad (5)$$

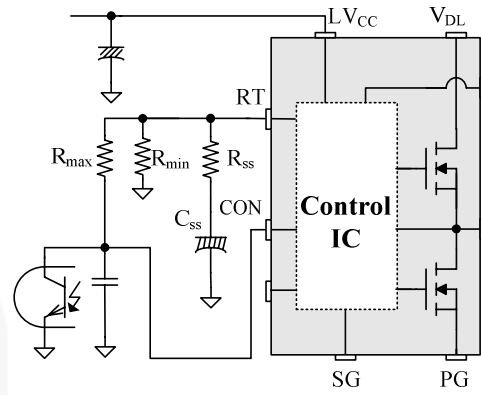


Figure 22. Control Pin Configuration for Pulse Skipping

**Remote On / Off:** When an auxiliary power supply is used for standby, the main power stage using FSFR-series can be shut down by pulling down the control pin voltage, as shown in Figure 23. R1 and C1 are used to ensure soft-start when switching resumes.

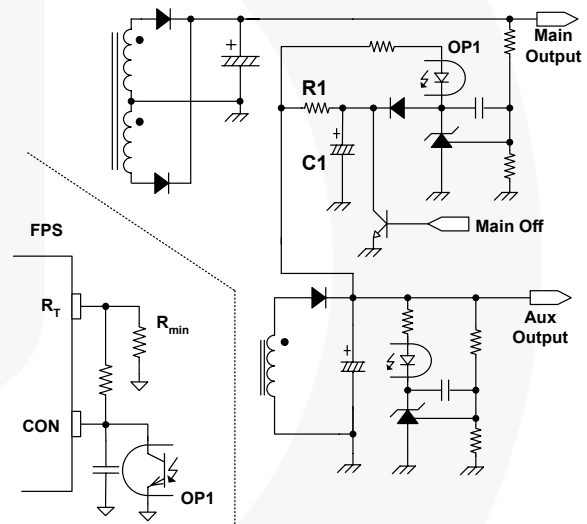


Figure 23. Remote On / Off Circuit

#### 4. Current Sensing Method

**Current Sensing Using Resistor:** FSFR-series senses drain current as a negative voltage, as shown in Figure 24 and Figure 25. Half-wave sensing allows low power dissipation in the sensing resistor, while full-wave sensing has less switching noise in the sensing signal.

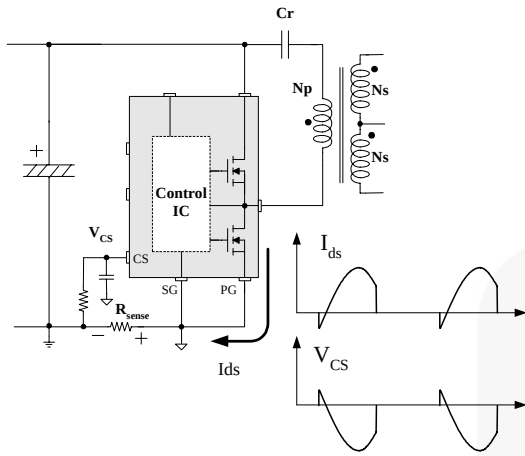


Figure 24. Half-Wave Sensing

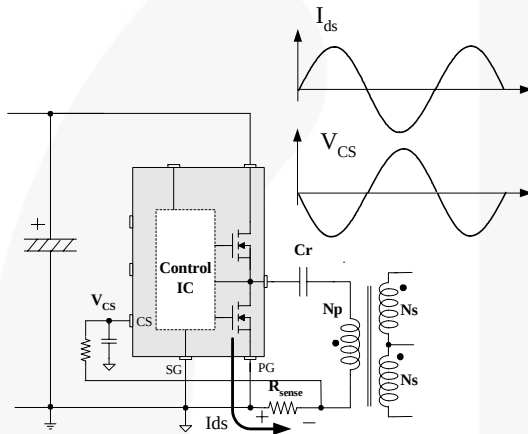


Figure 25. Full-Wave Sensing

**Current Sensing Using Resonant Capacitor Voltage:** For high-power applications, current sensing using a resistor may not be available due to the severe power dissipation in the resistor. In that case, indirect current sensing using the resonant capacitor voltage can be a good alternative because the amplitude of the resonant capacitor voltage ( $V_{Cr}^{p-p}$ ) is proportional to the resonant current in the primary side ( $I_p^{p-p}$ ) as:

$$V_{Cr}^{p-p} = \frac{I_p^{p-p}}{2\pi f_s C_r} \quad (6)$$

To minimize power dissipation, a capacitive voltage divider is generally used for capacitor voltage sensing, as shown in Figure 26.

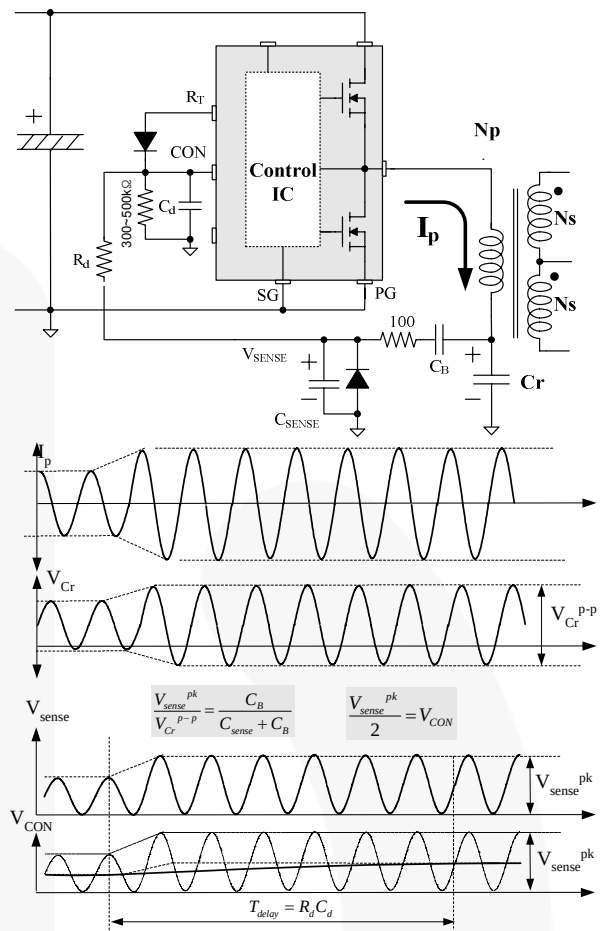


Figure 26. Current Sensing Using Resonant Capacitor Voltage

**5. Protection Circuits:** The FSFR-series has several self-protective functions, such as Overload Protection (OLP), Over-Current Protection (OCP), Abnormal Over-Current Protection (AOCP), Over-Voltage Protection (OVP), and Thermal Shutdown (TSD). OLP, OCP, and OVP are auto-restart mode protections; while AOCP and TSD are latch-mode protections, as shown in Figure 27.

**Auto-restart Mode Protection:** Once a fault condition is detected, switching is terminated and the MOSFETs remain off. When  $LV_{CC}$  falls to the  $LV_{CC}$  stop voltage of 11.3V, the protection is reset. The FPS resumes normal operation when  $LV_{CC}$  reaches the start voltage of 14.5V.



## Typical Application Circuit (Half-Bridge LLC Resonant Converter)

| Application | FPS™ Device | Input Voltage Range      | Rated Output Power | Output Voltage (Rated Current) |
|-------------|-------------|--------------------------|--------------------|--------------------------------|
| LCD TV      | FSFR2100U   | 400V (20ms Hold-up Time) | 192W               | 24V-8A                         |

### Features

- High efficiency ( >94% at 400V<sub>DC</sub> input)
- Reduced EMI noise through zero-voltage-switching (ZVS)
- Enhanced system reliability with various protection functions

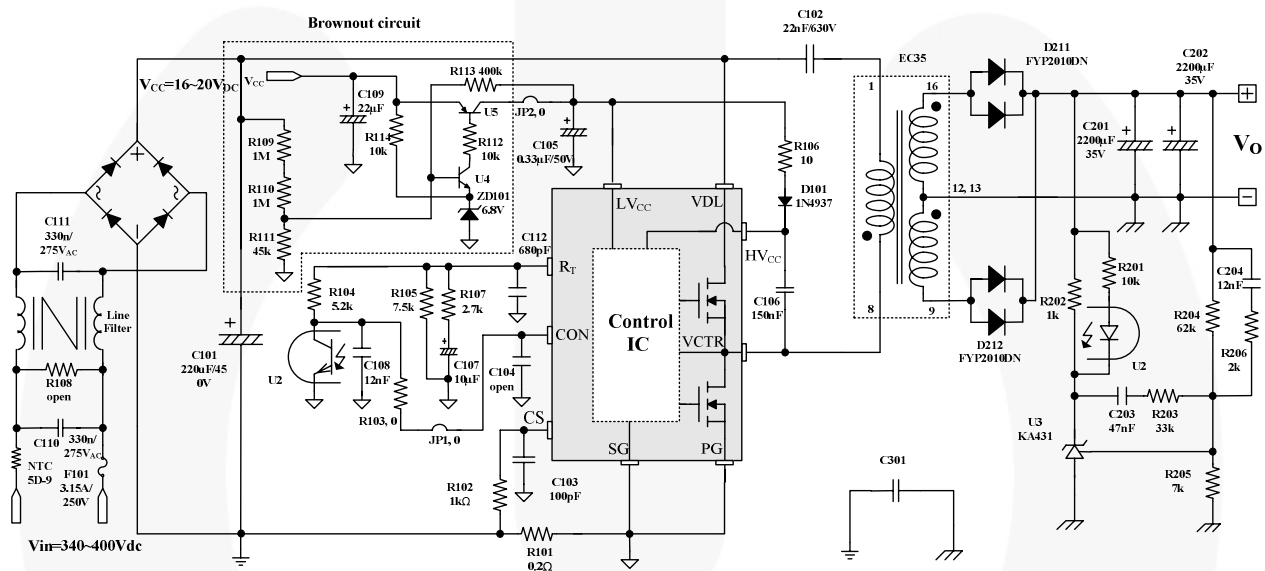


Figure 29. Typical Application Circuit

## Typical Application Circuit (Continued)

Usually, LLC resonant converters require large leakage inductance value. To obtain a large leakage inductance, sectional winding method is used.

- Core: EER3542 ( $A_e=107 \text{ mm}^2$ )
- Bobbin: EER3542 (Horizontal)

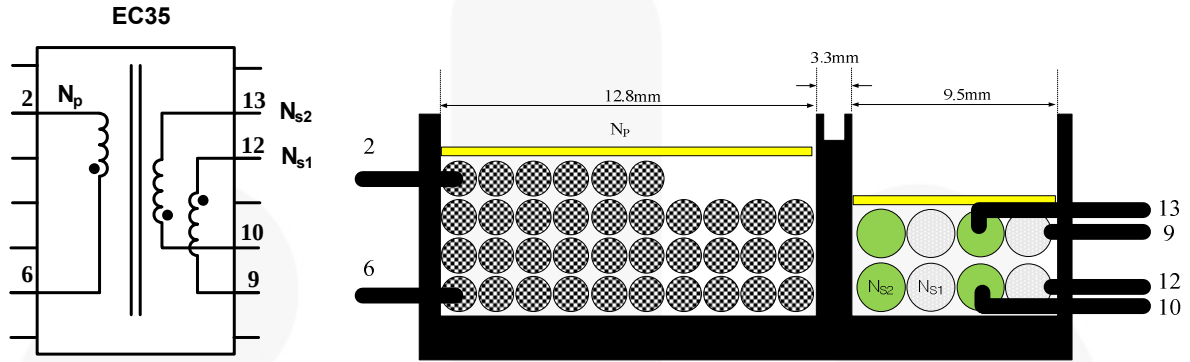


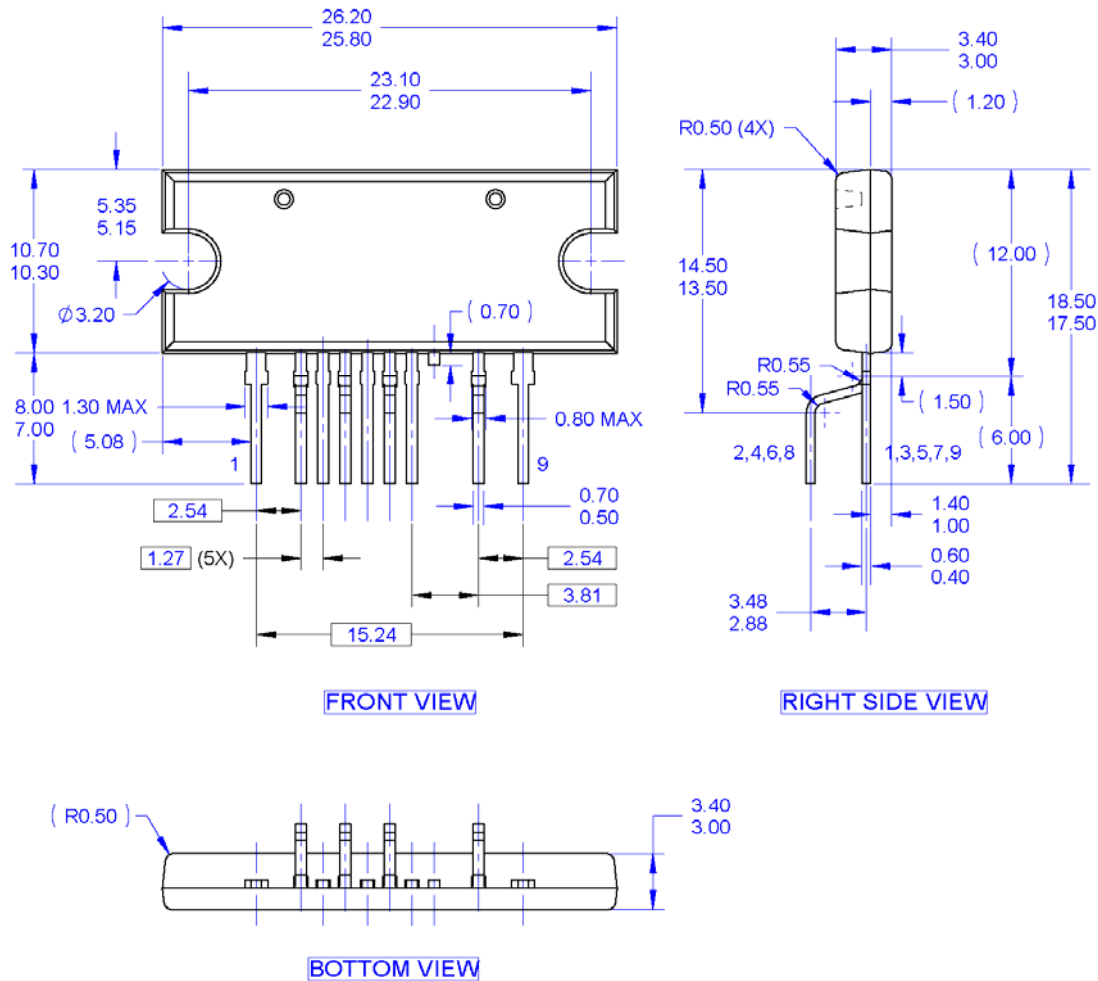
Figure 30. Transformer Construction

|          | Pins (S → F) | Wire                 | Turns | Note            |
|----------|--------------|----------------------|-------|-----------------|
| $N_p$    | 8 → 1        | 0.12φ×30 (Litz Wire) | 36    |                 |
| $N_{s1}$ | 12 → 9       | 0.1φ×100 (Litz Wire) | 4     | Bifilar Winding |
| $N_{s2}$ | 16 → 13      | 0.1φ×100 (Litz Wire) | 4     | Bifilar Winding |

|                                          | Pins | Specifications | Remark                              |
|------------------------------------------|------|----------------|-------------------------------------|
| Primary-Side Inductance ( $L_p$ )        | 1—8  | 630μH ± 5%     | 100kHz, 1V                          |
| Primary-Side Effective Leakage ( $L_r$ ) | 1—8  | 135μH ± 5%     | Short One of the secondary Windings |



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Figure 31. 9-SIP Package

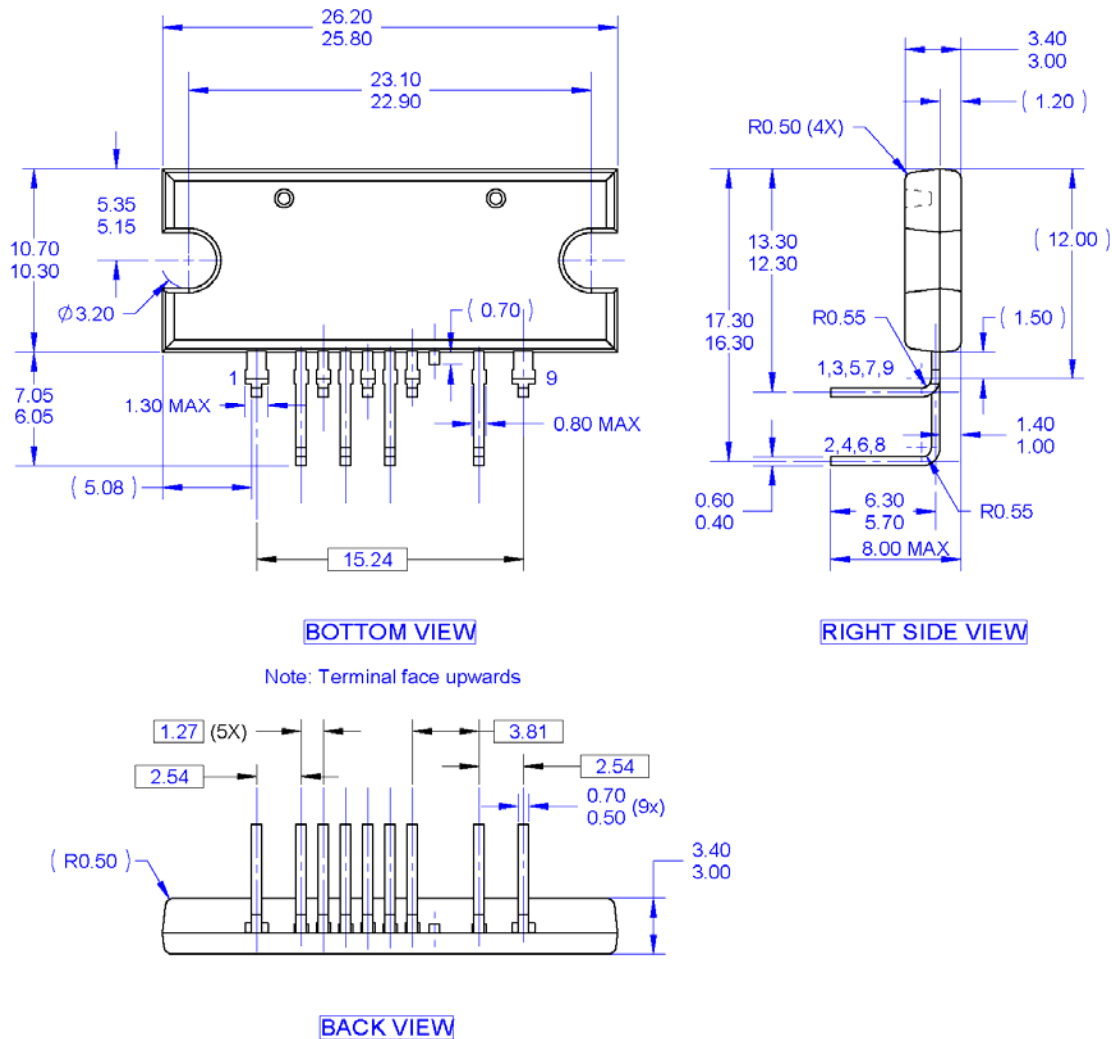
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**Figure 32. 9-Lead, SIP Module, L-Forming, 3.2x10.5x26mm Body**

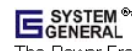
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